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**Davydov splitting and resonance Raman studies of few-layer MoSe<sub>2</sub>** KANGWON KIM, JAE-UNG LEE, DAHYUN NAM, HYEONSIK CHEONG, Sogang Univ — We conducted Raman investigation of few-layer MoSe<sub>2</sub> with eight different excitation energies. New peaks that appeared only near resonance with various exciton states were analyzed, and the modes were assigned. We observed splitting of intralayer A<sub>1g</sub>, E<sub>1g</sub>, and A<sub>2u</sub> modes for some excitation energies near resonances. This splitting is called ‘Davydov splitting’ and caused by interlayer interaction. By fitting the spectral positions of interlayer shear and breathing modes and Davydov splitting of intralayer modes to a linear chain model, we extracted the strength of the interlayer interaction. We found that the second-nearest-neighbor interlayer interaction amounts to about 30% of the nearest-neighbor interaction for both in-plane and out-of-plane vibrations. In addition, we investigated resonance effects of each Raman mode. The resonance profiles of the Raman peaks reflected the joint density of states for optical transitions, but the symmetry of the exciton wave functions leads to selective enhancement of the A<sub>1g</sub> mode at the A exciton energy and the shear mode at the C exciton energy.

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